

Honeycomb-like ZnO/SnO₂ nanocomposite at nickel foam for high-performance asymmetric supercapacitors

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Supplementary Information

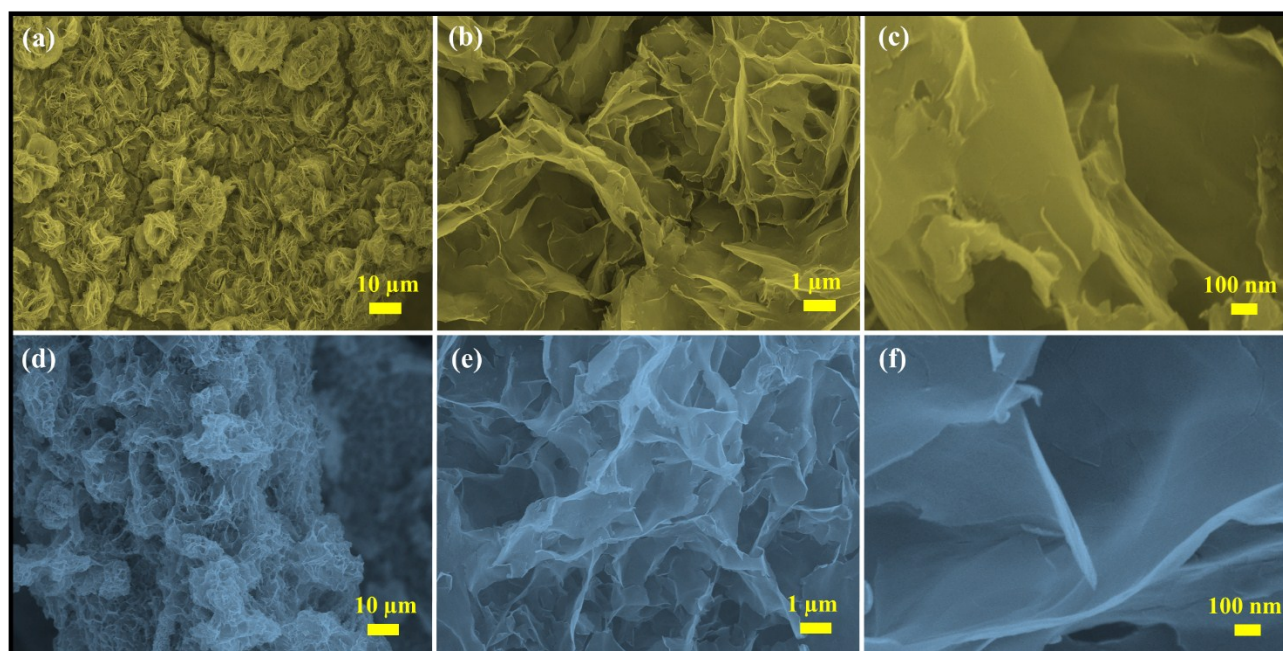


Fig. S1 SEM Images at different magnification: (a-c) ZnO (d-f) SnO₂.

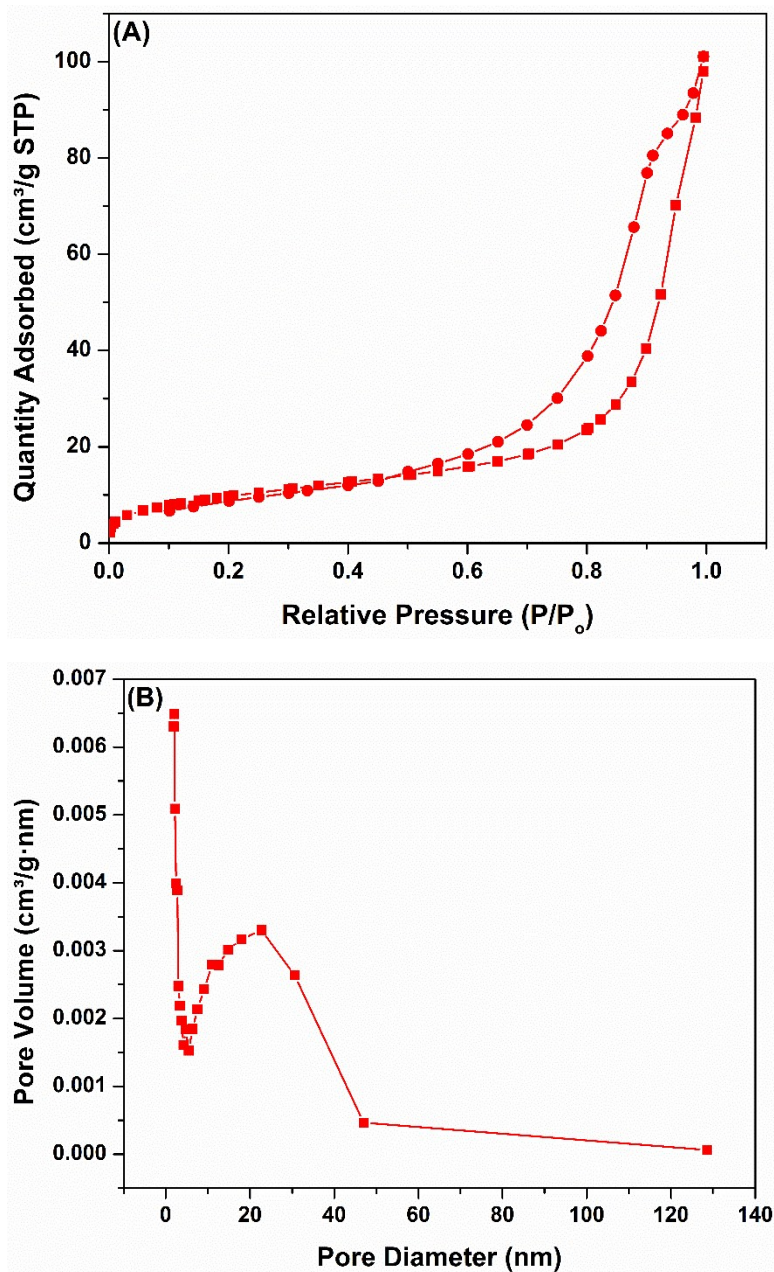


Fig. S2 N₂ adsorption-desorption isotherm of ZnO/SnO₂ nanocomposite (A), BJH pore size distribution of ZnO/SnO₂ nanocomposite (B).

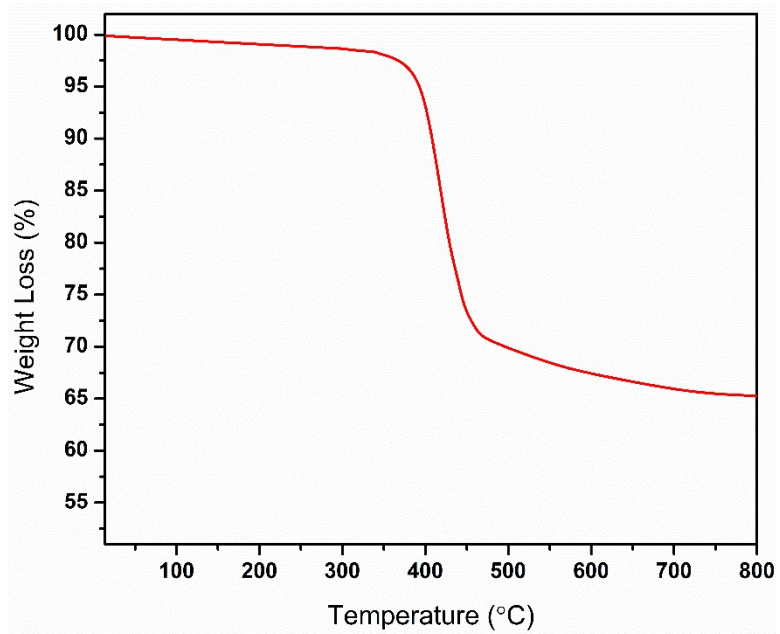


Fig. S3 TGA of ZnO/SnO₂ nanocomposite.

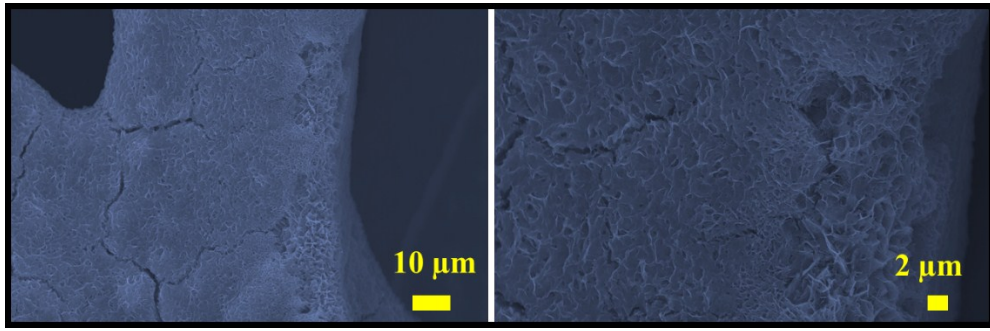


Fig. S4 SEM Images at different magnification after 7000 GCD.

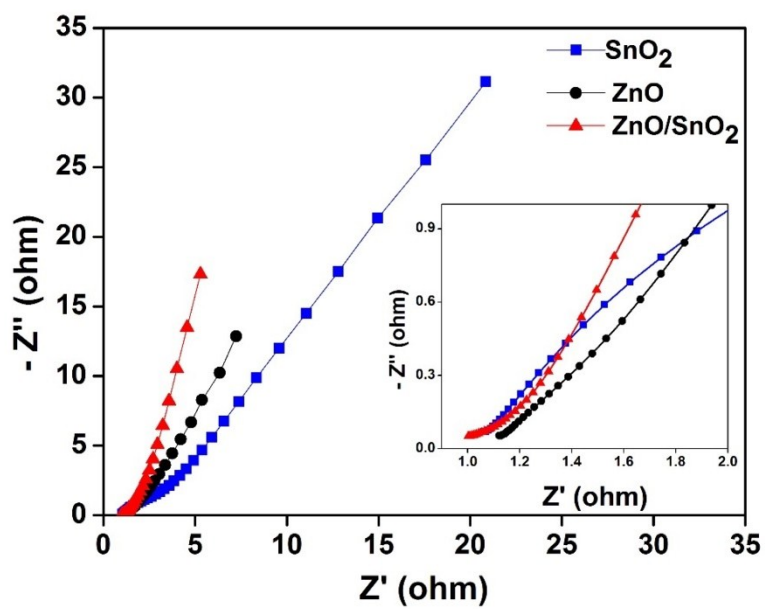


Fig. S5 Nyquist plot of ZnO, SnO₂ and ZnO/SnO₂ in 3M KOH.

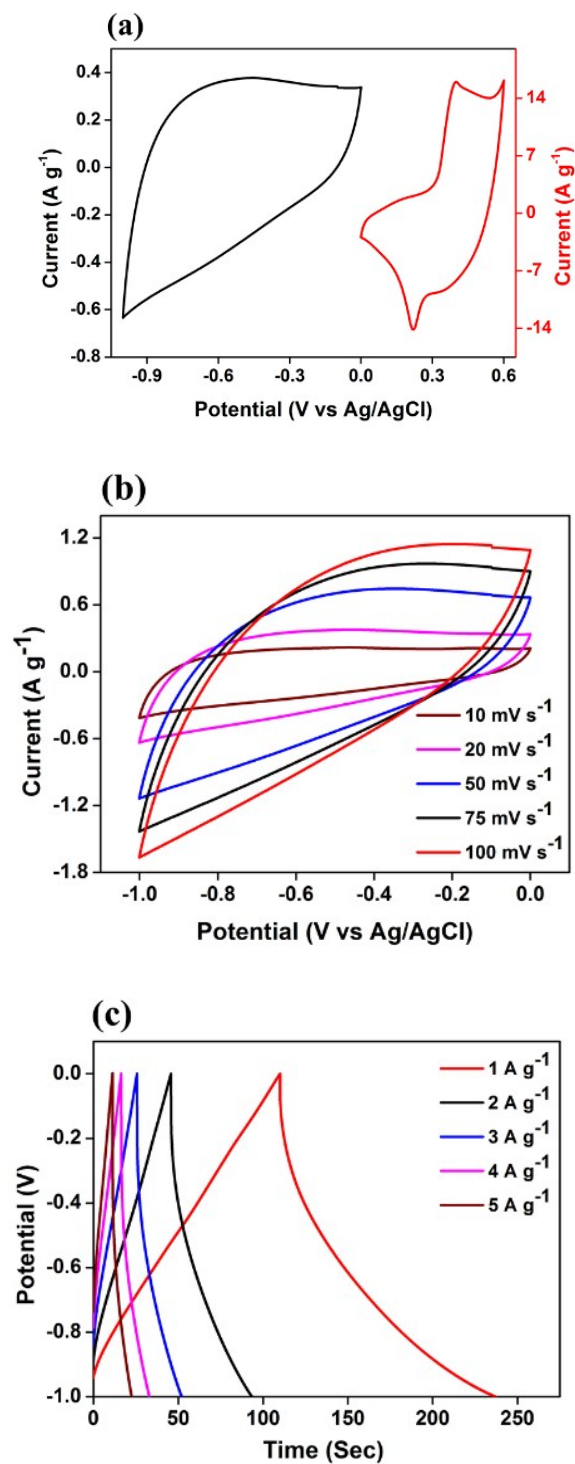


Fig. S6 Electrochemical performance of AC@NF in a 3M KOH electrolyte: (a) CV curves of ZNCO and AC@NF at 20 mV s^{-1} (b) GCD of AC@NF at current density of 1 to 5 A g^{-1} and (c) CV curves of AC@NF at different scan rate from 10 to 100 mV s^{-1} .

Table S1. Comparison of several Zinc and Tin oxide based electrode materials in the literature and this study.

Electrode	Electrolyte	Current density	Scan rate (mV s ⁻¹)	Specific capacitance/ Capacity	Ref.
NiO/ZnO	3 M KOH	1 A g ⁻¹		976 F g ⁻¹	1
ZnO/rGO	1M Na ₂ SO ₄	-	10	95 F g ⁻¹	2
ZnO-MnO ₂	1M Na ₂ SO ₄	0.5 A g ⁻¹	-	423 F g ⁻¹	3
MnO ₂ -ZnO	0.1M Na ₂ SO ₄	-	2	571 μF cm ⁻²	4
Core-shell ZnO-NiO	1 M KOH	5 mA cm ⁻²	-	4.1 F cm ⁻²	5
ZnO-NiO	1 M KOH	5 mA cm ⁻²	-	0.5 F cm ⁻²	5
ZnO-NiO	3 M KOH	-	5.8	649 F g ⁻¹	6
Sn ₂ O/G	6M KOH	-	5	818.6 F g ⁻¹	7
SnO ₂ /SWCNT	1 M Na ₂ SO ₄		6	320	8
SnO ₂ /Graphene	1 M Na ₂ SO ₄		5	363.3	9
ZnO/SnO ₂	3 M KOH	1	-	2,307 F g ⁻¹	This work

References

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